

400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor28 September 2017Product data sheet

1. General description

 $\label{eq:PNP-high-voltage-low-V} PNP \ high-voltage \ low-V_{CEsat} \ Breakthrough \ In \ Small \ Signal \ (BISS) \ transistor \ in \ a \ SOT89 \ (SC-62) \ medium \ power \ and \ flat \ lead \ Surface-Mounted \ Device \ (SMD) \ plastic \ package.$

NPN complement: PBHV8540X

2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- AEC-Q101 qualified

3. Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch mode power supply

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-400	V
I _C	collector current			-	-	-0.5	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-	-1	А
h _{FE}	DC current gain	V_{CE} = -5 V; I _C = -20 mA; T _{amb} = 25 °C		140	-	450	
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -200 mA; I_{B} = -40 mA; T_{amb} = 25 °C	[1]	-	-	2000	mΩ

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$

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5. Pinning information

Table 2.	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		C .
2	С	collector		в
3	В	base	3 2 1 SOT89	E sym132

6. Ordering information

Table 3. Ordering information						
Type number	Package	ackage				
	Name	Description	Version			
PBHV9540X	SOT89	plastic surface-mounted package; die pad for good heat transfer; 3 leads	SOT89			

7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PBHV9540X	%4H

[1] % = placeholder for manufacturing site code

8. Limiting values

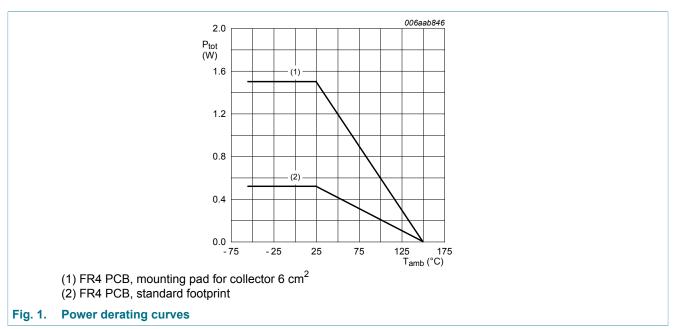
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-400	V
V _{CEO}	collector-emitter voltage	open base		-	-400	V
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		-	-400	V
V _{EBO}	emitter-base voltage	open collector		-	-7	V
I _C	collector current			-	-0.5	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-1	А
I _B	base current			-	-250	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.52	W
			[2]	-	1.5	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

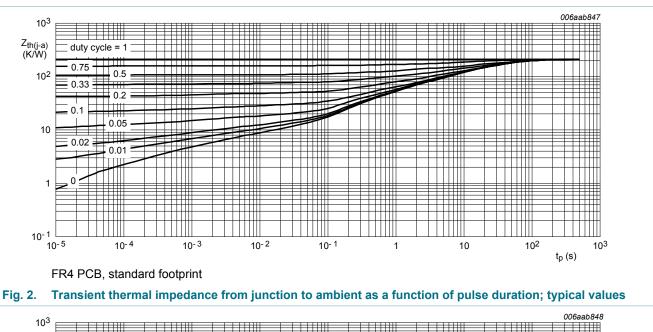


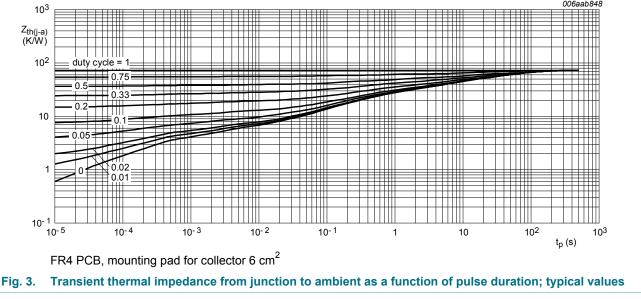
9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		-	[1]	-	-	240	K/W
	-		[2]	-	-	83	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	20	-	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².





10. Characteristics

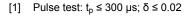
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I_{C} = -100 µA; I_{E} = 0 A; T_{amb} = 25 °C		-400	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I_{C} = -2.5 mA; I_{B} = 0 A; T_{amb} = 25 °C		-400	-	-	V
V _{(BR)CES}	collector-emitter breakdown voltage (base shorted)	I_{C} = -2.5 mA; V_{BE} = 0 V; T_{amb} = 25 °C		-400	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage (collector open)	I_E = -100 µA; I_C = 0 A; T_{amb} = 25 °C		-7	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = -320 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	current	V _{CB} = -320 V; I _E = 0 A; T _j = 150 °C		-	-	-10	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -320 V; V_{BE} = 0 V; T_{amb} = 25 °C		-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = -7 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE} DC current gain	V_{CE} = -5 V; I _C = -20 mA; T _{amb} = 25 °C		140	-	450		
		V_{CE} = -5 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	140	-	400	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = -100 mA; I_{B} = -20 mA; T_{amb} = 25 °C	[1]	-	-	-250	mV
		I _C = -200 mA; I _B = -40 mA;	[1]	-	-	-400	mV
R _{CEsat}	collector-emitter saturation resistance	T _{amb} = 25 °C		-	-	2000	mΩ
V _{BEsat}	base-emitter saturation voltage	I_{C} = -100 mA; I_{B} = -10 mA; T_{amb} = 25 °C	[1]	-	-	-0.9	V
		I_{C} = -200 mA; I_{B} = -40 mA; T_{amb} = 25 °C	[1]	-	-	-1	V
V _{BE}	base-emitter voltage	V_{CE} = -10 V; I _C = -200 mA; T _{amb} = 25 °C	[1]	-	-	-0.9	V
t _d	delay time	$V_{CC} = -6.2 \text{ V}; I_{C} = -100 \text{ mA};$		-	60	-	ns
t _r	rise time	I _{Bon} = -10 mA; I _{Boff} = 20 mA; T _{amb} = 25 °C		-	3650	-	ns
t _{on}	turn-on time			-	3710	-	ns
t _s	storage time			-	810	-	ns
t _f	fall time			-	900	-	ns
t _{off}	turn-off time			-	1710	-	ns
f _T	transition frequency	V _{CE} = -5 V; I _C = -50 mA; f = 100 MHz; T _{amb} = 25 °C		-	65	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	14	-	pF

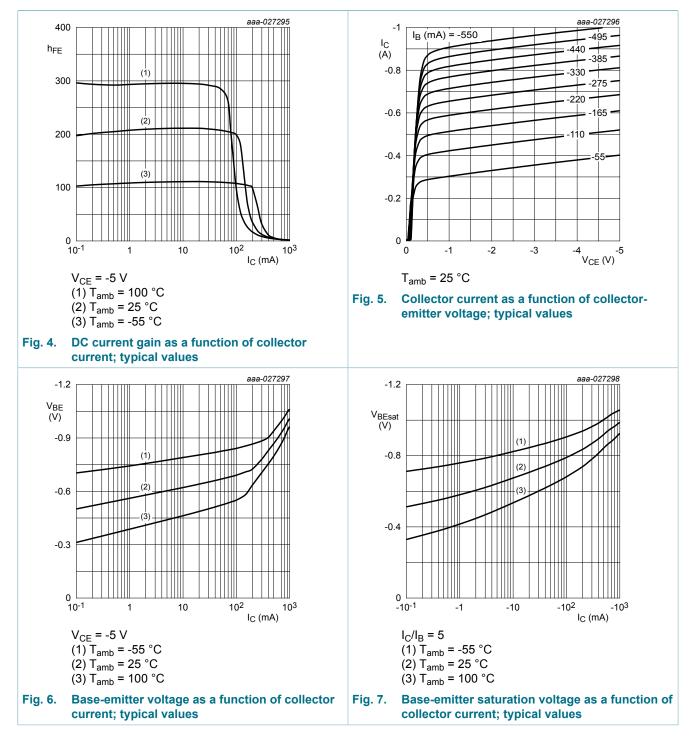
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
C _e	emitter capacitance	V_{EB} = -0.5 V; I _C = 0 A; i _c = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	235	-	pF

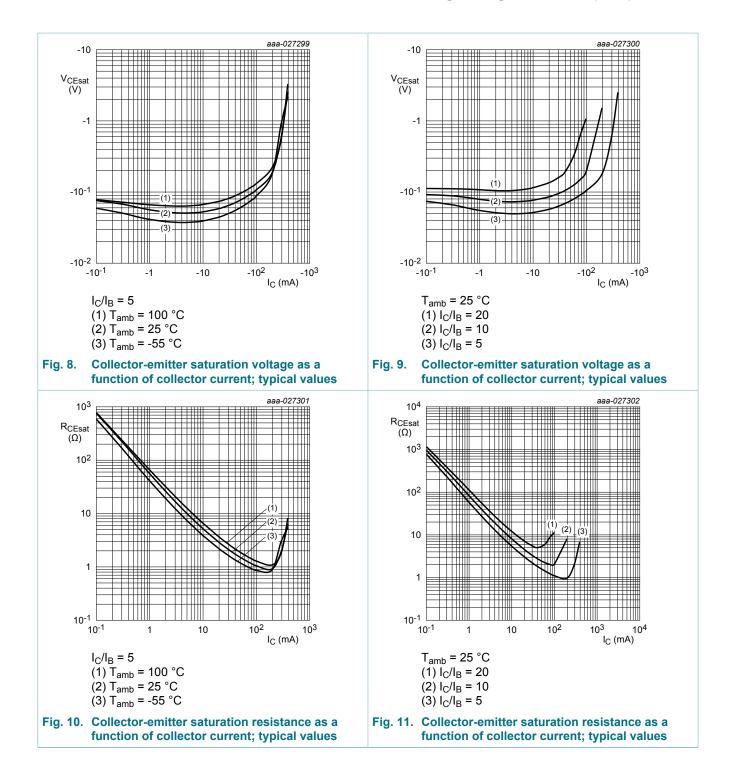




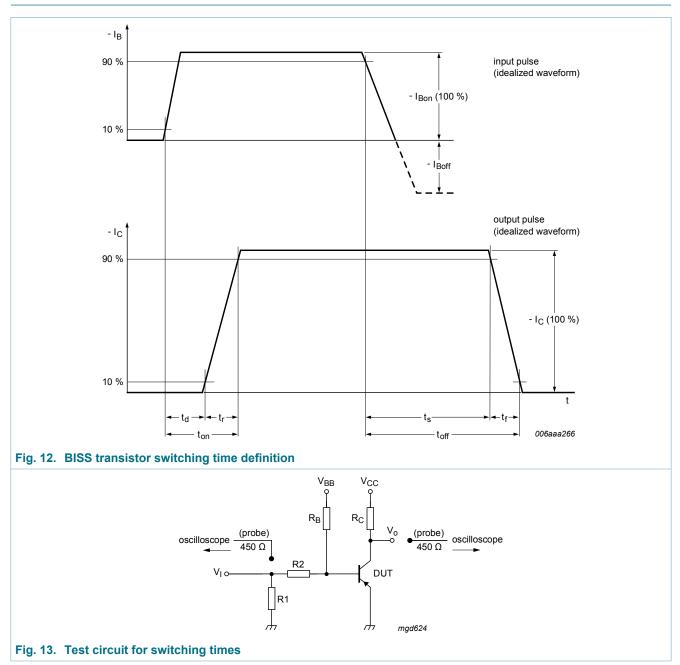
Nexperia

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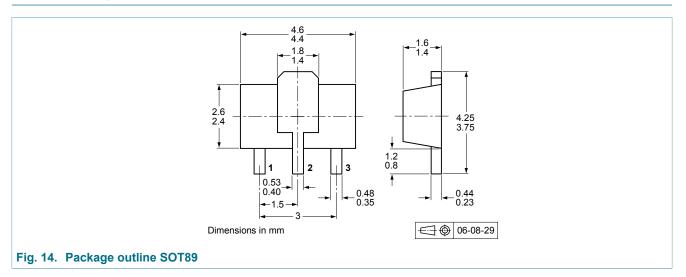


11. Test information

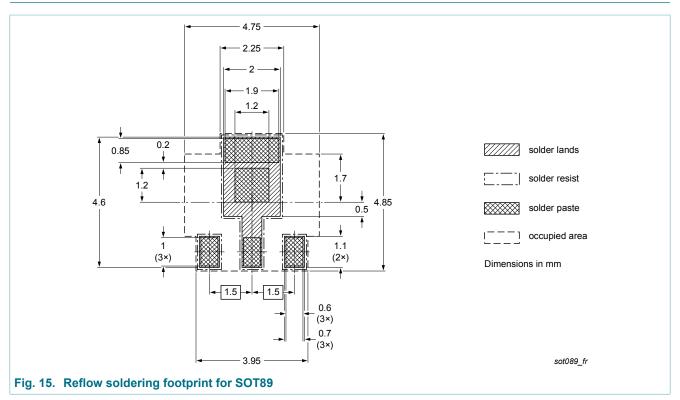
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

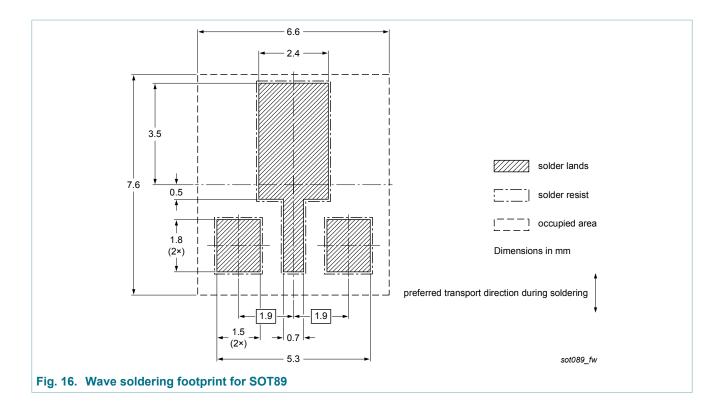


13. Soldering



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14. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PBHV9540X v.1	20170928	Product data sheet	-	-	

400 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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